L	Hits	Search Text	DB	Time stamp
Number	2	//#6207169#\ or /#6292042#\\ nw	USPAT;	2003/01/27
-	2	(("6297168") or ("6383943")).PN.	US-PGPUB	14:02
-	883	(BARC or ARC or antireflect\$4 or anti adj	USPAT;	2003/04/21
		reflect\$4) same (resist or photoresist) same (IMD or dielectric)	US-PGPUB; EPO; JPO;	18:45
		·	IBM_TDB	
-	169	((BARC or ARC or antireflect\$4 or anti adj reflect\$4) same (resist or	USPAT; US-PGPUB;	2003/04/18
	,	photoresist) same (IMD or dielectric))	EPO; JPO;	17.10
		and (BARC or ARC or antireflect\$4 or anti	IBM_TDB	
		adj reflect\$4) near3 (conformal or via or opening or trench or groove or sidewall)		
-	94	(((BARC or ARC or antireflect\$4 or anti	USPAT;	2003/04/18
		adj reflect\$4) same (resist or photoresist) same (IMD or dielectric))	US-PGPUB; EPO; JPO;	17:12
	•	and (BARC or ARC or antireflect\$4 or anti	IBM_TDB	
<u>}</u>		adj reflect\$4) near3 (conformal or via or	_	
D		opening or trench or groove or sidewall)) and (BARC or ARC or antireflect\$4 or anti		
Ö		adj reflect\$4) same etch\$3 near2 stop\$4		
BEST AVAILABLE COPY	75	((((BARC or ARC or antireflect\$4 or anti adj reflect\$4) same (resist or	USPAT; US-PGPUB;	2003/04/21 16:17
		photoresist) same (IMD or dielectric))	EPO; JPO;	10.17
9		and (BARC or ARC or antireflect\$4 or antiad) reflect\$4) near3 (conformal or via or	IBM_TDB	
		opening or trench or groove or sidewall))		
8		and (BARC or ARC or antireflect\$4 or anti		
>		adj reflect\$4) same etch\$3 near2 stop\$4) and (BARC or ARC or antireflect\$4 or anti		
		adj reflect\$4) same (silicon adj		
		oxynitride or "SiON" or titanium adj nitride or "Ti.sub."?"N.sub."? or "TiN"		
M		or "Ti" adj "N")		:
©	19	((((BARC or ARC or antireflect\$4 or anti	USPAT;	2003/04/18
		adj reflect\$4) same (resist or photoresist) same (IMD or dielectric))	US-PGPUB; EPO; JPO;	17:45
		and (BARC or ARC or antireflect\$4 or anti	IBM_TDB	
		adj reflect\$4) near3 (conformal or via or opening or trench or groove or sidewall))		
		and (BARC or ARC or antireflect\$4 or anti		
		<pre>adj reflect\$4) same etch\$3 near2 stop\$4) not ((((BARC or ARC or antireflect\$4 or</pre>		
		anti adj reflect\$4) same (resist or		
		photoresist) same (IMD or dielectric))		
		and (BARC or ARC or antireflect\$4 or anti- adj reflect\$4) near3 (conformal or via or		
		opening or trench or groove or sidewall))		
		and (BARC or ARC or antireflect\$4 or anti- adj reflect\$4) same etch\$3 near2 stop\$4)		
		and (BARC or ARC or antireflect\$4 or anti		
		adj reflect\$4) same (silicon adj oxynitride or "SiON" or titanium adj		
		nitride or "Ti.sub."?"N.sub."? or "TiN"		
	7.	or "Ti" adj "N"))	IICDAM.	2003/04/19
-	75	(((BARC or ARC or antireflect\$4 or anti adj reflect\$4) same (resist or	USPAT; US-PGPUB;	2003/04/18 17:45
		photoresist) same (IMD or dielectric))	EPO; JPO;	
	.	and (BARC or ARC or antireflect\$4 or antiad) reflect\$4) near3 (conformal or via or	IBM_TDB	
		opening or trench or groove or sidewall))		
		not ((((BARC or ARC or antireflect\$4 or		
		anti adj reflect\$4) same (resist or photoresist) same (IMD or dielectric))		
		and (BARC or ARC or antireflect\$4 or anti		
		<pre>adj reflect\$4) near3 (conformal or via or opening or trench or groove or sidewall))</pre>		
.		and (BARC or ARC or antireflect\$4 or anti		
		adj reflect\$4) same etch\$3 near2 stop\$4)		

-	714	((BAke or ARC or antireflect\$4 or anti	USPAT;	2003/04/18
		adj reflect\$4) same (resist or	US-PGPUB;	17:46
		photoresist) same (IMD or dielectric))	EPO; JPO;	
	İ	not (((BARC or ARC or antireflect\$4 or	IBM TDB	
	ľ	anti adj reflect\$4) same (resist or	_	
		photoresist) same (IMD or dielectric))		
}		and (BARC or ARC or antireflect\$4 or anti		
		adj reflect\$4) near3 (conformal or via or		
l		opening or trench or groove or sidewall))		
	42789		USPAT;	2003/04/21
-	42703	reflect\$4) with (via or hole or wall or	US-PGPUB;	10:18
		sidewall or opening or trench)	EPO; JPO;	10.10
		sidewall of opening of crencity		
		//DDDG DDG	IBM_TDB	2002 (04 (21
-	9	((BARC or ARC or antireflect\$4 or anti	USPAT;	2003/04/21
		adj reflect\$4) with (via or hole or wall	US-PGPUB;	10:19
		or sidewall or opening or trench)) and	EPO; JPO;	
		427/97.ccls.	IBM_TDB	
-	1	("6541367").PN.	USPAT;	2003/04/21
			US-PGPUB	16:17
-	0	100,000,000,000,000,000	USPAT;	2003/04/21
		TARC or BARC or ARC or antireflect\$4 or	US-PGPUB;	18:55
		anti adj reflect\$4) near5 (sidewall or	EPO; JPO;	
		side adj wall or hole adj wall or via	IBM_TDB	
		near2 wall or via near2 side or trench	_	
		near2 wall or trench near2 side or		
		conformal\$3) same (IMD or ILD or		
1		dielectric) not ((BARC or ARC or		
		antireflect\$4 or anti adj reflect\$4) same		
		(resist or photoresist) same (IMD or		
		dielectric))		
_	0	, ,	USPAT;	2003/04/21
		TARC or BARC or ARC or antireflect\$4 or	US-PGPUB;	18:58
		anti adj reflect\$4) near5 (sidewall or	EPO; JPO;	
		side adj wall or hole adj wall or via	IBM TDB	
		near2 wall or via near2 side or trench		
		near2 wall or trench near2 side or		
		conformal\$3) and (IMD or ILD or		,
1		dielectric) not ((BARC or ARC or		
		antireflect\$4 or anti adj reflect\$4) same		
		(resist or photoresist) same (IMD or		
	į	dielectric))		
1_	0	1	USPAT;	2003/04/21
-	1	TARC or BARC or ARC or antireflect\$4 or	US-PGPUB;	18:59
		anti adi reflect\$4) near5 (sidewall or		10.39
			EPO; JPO;	
		side adj wall or hole adj wall or via	IBM_TDB	1
	1	near2 wall or via near2 side or trench		
		near2 wall or trench near2 side or		
		conformal\$3) and (IMD or ILD or		
		dielectric)) not ((BARC or ARC or		
		antireflect\$4 or anti adj reflect\$4) same		
		(resist or photoresist) same (IMD or		
1	1	dielectric))		

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